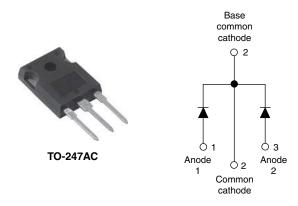
**Vishay Semiconductors** 



Hyperfast Rectifier, 2 x 30 A FRED Pt<sup>®</sup>



PRODUCT SUMMARY								
Package	TO-247AC							
I <sub>F(AV)</sub>	2 x 30 A							
V <sub>R</sub>	300 V							
V <sub>F</sub> at I <sub>F</sub>	1.25 V							
t <sub>rr</sub> typ.	See Recovery table							
T <sub>J</sub> max.	175 °C							
Diode variation	Common cathode							

#### **FEATURES**

- Hyperfast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47



- RoHS COMPLIANT HALOGEN
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

### **DESCRIPTIONS/APPLICATIONS**

VS-60CPH03PbF, VS-60CPH03-N3 series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS					
Repetitive peak reverse voltage	V <sub>RRM</sub>		300	V					
Average restified forward surrent	F(A)/)	T <sub>C</sub> = 143 °C	30						
Average rectified forward current total device			60	А					
Non-repetitive peak surge current per leg	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	300						
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C					

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	SYMBOL	YMBOL TEST CONDITIONS MIN. TYP. MAX. U							
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	300	-	-				
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	1.08	1.25	1.25 V			
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	0.92	1.00				
Deveree leekees eurrent	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	0.05	60				
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	20	300	μΑ			
Junction capacitance	CT	V <sub>R</sub> = 300 V	-	70	-	pF			
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	3.5	-	nH			

Revision: 30-Sep-11

Document Number: 94500

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST C	ONDITIONS	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 1.0 \text{ A}$	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$			55			
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	39	-	ns		
		T <sub>J</sub> = 125 °C		-	57	-			
Deals recovers ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	$I_F = 30 A$	-	2.8	-	A		
Peak recovery current		T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = - 200 A/µs V <sub>R</sub> = 200 V	-	7.5	-			
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	55	-	20		
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	214	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C			
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	0.5	0.9				
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	R <sub>thJA</sub> Typical socket mount		-	40	°C/W			
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.4	-				
Waight			-	6.0	-	g			
Weight			-	0.22	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)			
Marking device		Case style TO-247AC	60CPH03						



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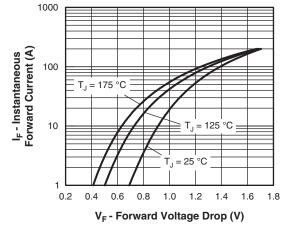


Fig. 1 - Typical Forward Voltage Drop Characteristics

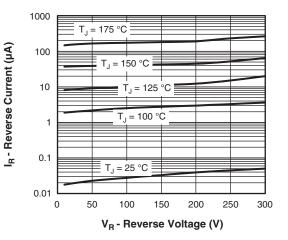


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

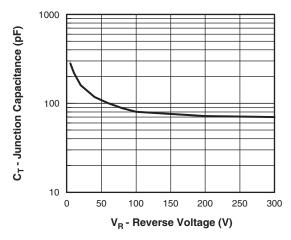
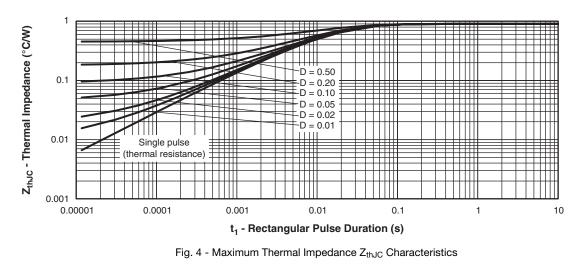


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



Revision: 30-Sep-11	3	Document Number: 94500
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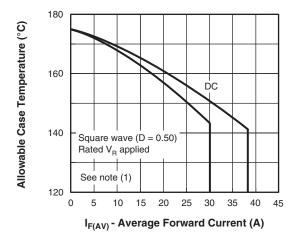


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

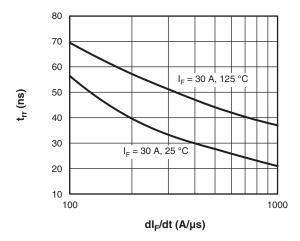


Fig. 6 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
  - $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward power loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \text{ at } (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \text{ (see fig. 6);} \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse power loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} (1 \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \text{ at } \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated V}_{\mathsf{R}} \end{array}$

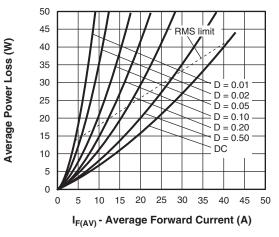


Fig. 7 - Forward Power Loss Characteristics

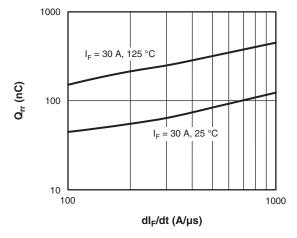


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



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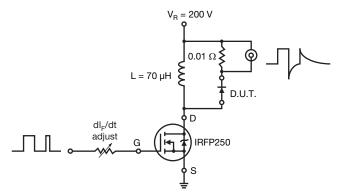
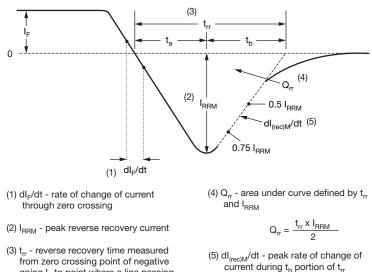
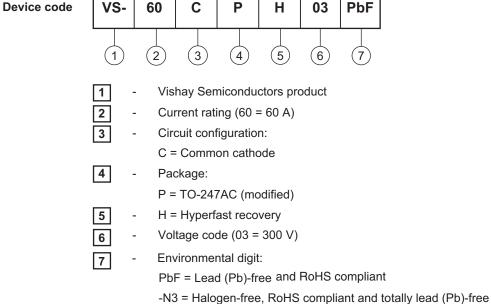


Fig. 9 - Reverse Recovery Parameter Test Circuit



from zero crossing point of negative going  $I_F$  to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$ extrapolated to zero current.

Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-60CPH03PbF	25	500	Antistatic plastic tube						
VS-60CPH03-N3	25	500	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95223					
Part marking information	TO-247ACPbF	www.vishay.com/doc?95226					
	TO-247AC-N3	www.vishay.com/doc?95007					

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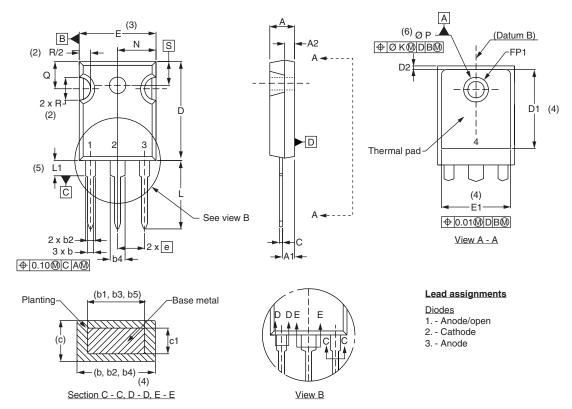


### **Outline Dimensions**





#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.72	-	0.540	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			FK	2.	54	0.0	)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.37	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ΦP	3.56	3.66	0.14	0.144	
с	0.38	0.86	0.015	0.034			Φ <b>P1</b>	-	6.98	-	0.275	
c1	0.38	0.76	0.015	0.030			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	]	R	4.52	5.49	1.78	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(4)</sup> Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC outline TO-247 with exception of dimension c

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